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Decoherence of cold atom ic gases in m agnetic m icro-traps

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We derive a model to describe decoherence of atom ic clouds in atom -chip traps taking the excited states of the trapping potential into account. We use this model to investigate decoherence for a single trapping welland for a pair of trapping wells that form the two arms of an atom interferom eter. Including the discrete spectrum of the trapping potential gives rise to a decoherence mechanism with a decoherence rate that scales like $1=r_0^4$ with the distance r_0 from the trap minimum to the wire.

I. IN TRODUCTION

Cold atom ic gases form an ideal system to test fundam ental quantum mechanical predictions. Progress in laser cooling made it possible to achieve previously inaccessible low temperatures in the nK-range (see, e.g., the Nobel lectures 1998 [1]). One of the most exciting consequences of this developm ent has been the creation of Bose-E instein condensates (BECs) [2, 3]. These have been manipulated by means of laser traps in various manners, e.g. vortices have been created or collisions of two BECs have been studied [4, 5, 6]. An interesting link to solid-state phenom ena has been established by creating optical lattices, in which a M ott transition has been theoretically predicted [7] and observed [8].

Recently, proposals to trap cold atom ic gases using m icrofabricated structures [9] have been realized experin entally [10, 11, 12] on silicon substrates, so-called atom chips. These systems combine the quantum mechanical testing ground of quantum gases with the great versatility in trapping geometries o ered by the microfabrication process. M icro-fabricated traps m ade it possible to split clouds of cold atom ic gases in a beam splitter geom etry [13], to transport wavepackets along a conveverbelt structure [14] and to accum ulate atom ic clouds in a storage ring [15]. Moreover, a BEC has been successfully transferred into a micro-trap and transported along a waveguide created by a current carrying microstructure fabricated onto a chip [16, 17, 18, 19]. Finally several suggestions to integrate an atom interferom eter for cold gases onto an atom chip have been put forward [20, 21, 22].

The high magnetic- eld gradients in atom-chip traps provide a strongly con ned motion of the atom ic quantum gases along the micro-structured wires. The atom ic cloud will be situated in close vicinity of the chip surface. As a consequence, there will be interactions between the substrate and the trapped atom ic cloud, and the cold gas can no longer be considered to be an isolated system. Recent experiments reported a fragmentation of cold atom ic clouds or BECs in a wire waveguide [19, 23, 24, 25] on reducing the distance between the wavepackets and the chip surface, showing that atom ic gases in wire traps are very sensitive to its environment. Experimental [26] and theoretical works [27] showed that there are losses of trapped atom s due to spin ips induced by the strong therm al gradient between the atom chip, held at room temperature, and the cold atom ic cloud. M oreover, R efs. [28, 29] studied the in uence of m agnetic near- elds and current noise on an atom ic wavepacket. C onsequences for the spatial decoherence of the atom ic w avepacket were discussed under the assumption that the transversal states of the one dimensional-waveguide are frozen out.

For wires of sm all width and height, as used for atom chip traps, the current uctuations will be directed along the wire. Consequently, the magnetic eld uctuations generated by these current uctuations, are perpendicular to the wire direction, inducing transitions between di erent transverse trapping states.

In this paper we will discuss the in uence of current uctuations in micro-structured conductors used in atom -chip traps. We derive an equation for the atom ic density matrix, that describes the decoherence and equilibration e ects in atom ic clouds taking transitions between di erent transversal trap states into account. We study decoherence of an atom ic state in a single waveguide aswellas in a system of two parallelwaveguides. Decoherence e ects in a pair of one-dimensional (1d) waveguides are of particularly high interest as this setup form s the basic building block for an on-chip atom interferom – eter [20, 21, 22].

O urm ain results can be summarized as follows. Considering current uctuations along the wire, we show that spatial decoherence along the guiding axis of the 1d-waveguide occurs only by processes including transitions between di erent transversal states. The decoherence rate obtained scales with the wire-to-trap distance r_0 as

 $1=\frac{4}{9}$. Applying our model to a double waveguide shows that correlations among the magnetic-eld uctuations in the left and right arm of the double waveguide are of m inor in portance. The change of the decoherence rate under the variation of the distance between the wires is dom inated by the geom etric rearrangem ent of the trap m inim a.

To arrive at these conclusions we proceed as follows. Section II will give a derivation of the kinetic equation describing the time evolution of an atom ic wavepacket in an array of N parallel 1d waveguides subject to uctuations in the trapping potential. We will then use this equa-

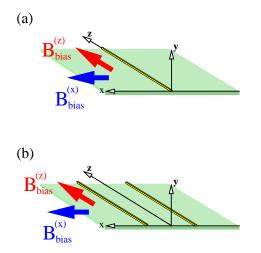


FIG. 1: Setup of the atom chip showing directions of the wires and the magnetic bias elds needed to form the trapping potential. (a) Single-wire trap. (b) D ouble-wire trap.

tion of motion in Section III to study the speci c cases of a single 1d waveguide and a pair of 1d waveguides. Spatial decoherence and equilibration e ects in the single and double waveguide will be discussed. Finally we sum marise and give our conclusions in Section IV.

II. EQUATION FOR THE DENSITY MATRIX

The trapping potential of a micro-structured chip is produced by the superposition of a hom ogeneous magnetic eld and the magnetic eld induced by the current in the conductors of the micro-structure. A toms in a low - eld seeking hyper ne state 5 i will be trapped in the magnetic eld minimum [30]. The interaction of the atom with the magnetic eld is

$$V(x) = hSj \beta iB(x);$$
 (1)

assuming that the Larm or precession of the trapped atom is much faster than the trap frequency and, hence, the magnetic moment of the atom can be replaced by its mean value hS j β i.

M any di erent wire- eld con gurations will lead to an atom trap [31, 32]. W e will concentrate on systems in which the trapping eld is produced by an array of parallel wires, see Fig. 1 for a single or double-wire trap. A hom ogeneous bias eld is applied parallel to the surface on which the wires are mounted. An exam ple for the resulting eld distribution for the single-wire trap is shown in Fig. 2.

A. Stochastic equation for the density m atrix

The quantum mechanical evolution of a cold atom ic cloud is described by a density matrix. The time evolution of the density matrix $(x;x^0;t)$ is given by the von

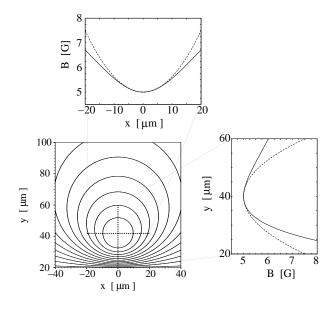


FIG.2: Contourplot of the magnetic eld of the single-wire trap for $B_{\rm bias}^{(x)} = 10$ G, $B_{\rm bias}^{(z)} = 5$ G, and I = 0:1A. The upper (right) plot shows a horizontal (vertical) cut through the potential minimum. The dashed lines in the upper and the right plot show the harm onic approximation to the trapping eld.

Neum ann equation

$$ih\frac{\theta}{\theta t} = [H;]; \qquad (2)$$

where H is the Ham iltonian of an atom in the trapping potential:

$$H = \frac{p^2}{2m} + V_t(r_?) + V(x;t) :$$
 (3)

Here, $V_t(r_?)$ is the conning potential which we will assume to be constant along the trap, and $r_?$ denotes the coordinate perpendicular to the direction of the current-carrying wire or the wave guide. The last term V(x;t) is a random uctuation term induced by the current noise.

W e will formulate the problem for a system of N parallel quasi-1d m agnetic traps generated by a set of M parallel wires on the chip (in general, N \leftarrow M since som e of the magnetic - eld m inim a may merge). The num ber of parallel trapping wells is included in the structure of the con ning potential V_t (r_?). In all further calculations we will assume that the surface of the atom chip is in the x-2plane and that the atom s are trapped in the half space y > 0 above the chip. The wires on the atom chip needed to form the trapping eld, are assumed to be aligned in 2-direction.

In position representation for the density matrix the von Neumann equation reads

$$ih_{\underline{\theta}t}^{\underline{\theta}} \quad (x; x^{0}; t) = \int_{2m}^{n} \frac{d^{2}}{dx^{2}} \frac{d^{2}}{dx^{2}} + V_{t}(r_{2}) \quad (4)$$

$$V_{t}(r_{2}^{0}) + V(x; t) \quad V(x; t) \quad (x; x^{0}; t) :$$

To derive a quasi-1d expression for Eq. (4) we expand the density m atrix in eigenmodes of the transverse potential $_{n}$ (r?):

$$(x;x^{0};t) = \sum_{n,m}^{X} (r_{2}) m (r_{2}^{0}) nm (z;z^{0};t) : (5)$$

Here, the channel index n labels the transverse states of the trapping potential. The transverse wavefunctions

 $_{n}$ (r_?) are chosen mutually orthogonal and are eigenfunctions of the transverse part of the Ham iltonian in Eq. (3) in the sense that

$$\frac{h^2}{2m}r_{r_2}^2 + V_t(r_2) \qquad _n(r_2) = E_n \qquad _n(r_2) : \qquad (6)$$

The decomposition (5) in transverse and longitudinal components of the density matrix is now inserted in the von N eum ann equation, Eq. (4). Making use of the orthogonality and the completeness of the transverse states $_{n}$ (r_{2}) we obtain a one-dimensional equation for the evolution of the density matrix:

$$ih\frac{\theta}{\theta t} + \frac{h^{2}}{2m} \frac{d^{2}}{dz^{2}} \frac{d^{2}}{dz^{0}} = \begin{bmatrix} S_{\ln}(z;t) \\ n \\ k \end{bmatrix} \begin{bmatrix} z_{2}z^{0};t \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} S_{\ln}(z;t) \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} S_{2}z^{0};t \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \\ z_{2}z^{0};t \end{bmatrix} = \begin{bmatrix} z_{2}z^{0};t \\ z_{$$

Here the abbreviation $E_{lk} = E_1 - E_k$ was introduced for the di erence of transverse energy levels, and the uctuations S_{nk} (z) are de ned as

$$S_{nk}(z;t) = dr_{?} n(r_{?}) V(x;t)_{k}(r_{?}) : (8)$$

The left-hand side of the reduced von Neum ann equation, Eq. (7), describes the evolution of an atom wavefunction in the non- uctuating trapping potential and we will hereafter abbreviate this part by (ih (f_{lk})). The term s on the right-hand side of Eq. (7) contain the in uence of the potential uctuations.

The uctuations of the con ning potential are described by the matrix elements $S_{nk}(z;t)$ which imply transitions between di erent discrete transverse energy levels induced by the uctuating potential. The in uence of the uctuating potential onto the longitudinalm otion of the atom ic cloud is included in the z dependence of $S_{nk}(z;t)$.

${\tt B}$. A veraged equation of m otion for the density $${\tt m}$$ atrix

In this section we derive the equation of motion describing the evolution of the density matrix h i averaged over the potential uctuations [33, 34]. To keep the expressions compact we rewrite Eq. (7) as

$$ih Q H' = S';$$
 (9)

where the spatial coordinates x, x^0 , time t and all indices have been suppressed. The components of the quantities H and S are dened as

$$\mathbf{H}_{lkij} = \mathbf{H}_{lk\ li\ kj}; \tag{10}$$

$$S_{lkij} = S_{li}(z;t)_{kj} \qquad S_{jk}(z^{0};t)_{li}: \qquad (11)$$

The product in (9) has the meaning $A^{r} = {P \atop ij} A_{lkij} ij$. The stochastic equation (9) for the density matrix is averaged over the uctuating potential using the standard cum ulant expansion [34]. Writing the time arguments again we obtain

$$ih (\ell H h (t) i = h S (t) ih (t) i \frac{i}{h} dt^{0} hh S (t) e^{\frac{i}{h} H^{t} t^{0}} S (t t) ii e^{\frac{i}{h} H^{t} t^{0}} h (t) i:$$
(12)

Here, the brackets h i denote the averaging over all realisations of the potential uctuations and the double brackets h ii denote the second cumulant. We can take the mean value of the potential uctuation h V i to zero, since the static potential is already included in the H am iltonian on the left hand side of Eq. (12) and, hence, the rst term on the right-hand side of Eq. (12) vanishes.

Reinserting the explicit expressions for H', S' leads to the desired equation of motion for the density matrix

The kernel K $_{ij}$ (z z; z' z'; t) is the Fourier transform of

which can be explicitly evaluated, but this has no advantage for our further discussion.

$$K_{ij}(q;q^{0};t) = \exp \qquad \frac{ih}{2m} q^{2} q^{2} t \frac{i}{h} E_{ij}t ;$$
(14)

Equation (13) is the main result of this section. It describes the evolution of the density matrix in a quasi-1d waveguide under the in uence of an external noise source. It is valid for an arbitrary form of the transverse con ning potential, thus, in particular, for single and double wire traps. The main input is the external noise correlator and its e ect on the trapped atom s. The noise correlator depends on the concrete wire con guration. Below we will derive a simpli ed form of the equation of motion (13) under the assumption that the time scale characterizing the uctuations is much shorter than the time scales of the atom ic motion.

C. Noise correlation function

W e will now derive the noise correlator for our speci c system and use Eq. (13) to study the dynamics. As we are interested in the coherence of atom s in an atom -chip trap, we will consider the current noise in the wires as the decoherence source. F luctuations of the m agnetic bias elds $B_{\rm bias}^{(x)}$ and $B_{\rm bias}^{(z)}$, needed to form the trapping potential, will be neglected.

U sing the approximation of a 1d wire, the uctuating current density can be written as

$$j(x;t) = I(z;t)$$
 (x) (y); (15)

where \hat{z} is the unit vector in \hat{z} -direction. The uctuations of the current density are dened by $j(x;t) \quad j(x;t)$ hj(x)i. It is su cient to know h I(z;t) I($\hat{z};t^0$) it o obtain the full current density correlation function h $j(x) \quad j(\hat{x})$ i. Note, that the average currents are already included in the static potential V_t (r_2).

The restriction of j to the 2 direction is a reasonable assum ption since we consider m icro-structured w ires with small cross-section $A = l_w l_h$, i.e. wires with widths l_w and heights la much smaller than the trap-to-wire distance r₀. Transversal current uctuations lead to surface charging and thus to an electrical eld which points in opposite direction to the current uctuation. This surface charging e ect will suppress uctuations which are slow compared to $!_{RC} =$ $= 0 l_w$. Here, is the conductivity of the wire, 0 the (vacuum) dielectric constant, 1A is the screening length in the metal. This and leads to RC –frequencies of $!_{RC}$ 10¹³H z for w ire w idths of $l_{w} = 10$ m and typical values for the conductivity in a metal.

The characteristic time scale for the atom ic motion in the trap is given by the frequency of the trapping potential ! 10^{4} Hz. Thus, considering atom ic traps with ! $!_{RC}$ the current uctuations can be taken along 2 as a direct consequence of the quasi-one-dimensionality of the wire.

The current uctuations are spatially uncorrelated as they have their origin in electron scattering processes. Hence, the correlator h I(z) I(2°) i has the form [35, 36]

h I(z;t) I(
$$\hat{z}$$
;t⁰)i = 4k_BT_e (z) A (z \hat{z}) c(t \hat{t}):
(16)

Here, k_B is the Boltzm ann constant. The e ective noise tem perature is given by [35, 36]

$$\begin{array}{c} Z \\ T_{e} (z) = dE f(E;z) [1 f(E;z)]; \end{array}$$
 (17)

where f (E;z) is the energy-and space-dependent nonequilibrium distribution function. A nite voltage across the wire induces a change in the velocity distribution of the electrons and the electrons are thus no longer in therm al equilibrium. Nevertheless, the deviation from an equilibrium distribution is smallat room temperature due to the large num ber of inelastic scattering processes. The e ective tem perature Te accounts for possible nonequilibrium e ects such as shot noise. How ever, contributions of non-equilibrium e ects to the noise strongly depend on the length L of the wire com pared to the characteristic inelastic scattering lengths. E.g. strong electronphonon scattering leads to an energy exchange between the lattice and the electrons. The non-equilibrium distribution is 'cooled' to an equilibrium distribution at the phonon temperature. Thus, non-equilibrium noise sources, such as shot noise, are strongly suppressed for wires much longer than the electron-phonon scattering length lep and the noise in the wire is essentially given by the equilibrium Nyquist noise [35, 37, 38]. As the wire lengths used in present experiments are much longer than 300K in all our calculations. lep,weTe

Finally,

$$_{c}(t) = \frac{1}{t^{2} + \frac{2}{c}}$$
 (18)

is a representation of the delta function. The correlation time $_{\rm c}$ is given by the time scale of the electronic scattering processes.

D. Sim pli ed equation of motion

The dom inating source of the current noise in the wires is due to the scattering of electrons with phonons, electrons and in purities. These scattering events are correlated on a tim e scalem uch shorter than the characteristic tim e scales of the atom ic system. This separation of tim e scales allow s us to simplify the equation of motion (13).

As a consequence of Eq. (16), the correlation function of the uctuating potential will be of the form

h V (x;t) V ($x^{2};t^{0}$) i= $_{c}$ (t t) h V (x) V (x^{0}) i: (19)

Using Eq. (8) we obtain

h
$$S_{im}$$
 (z;t) $S_{nj}(z^{0};t^{0})i = _{c}(t t^{0})h S_{im}(z) S_{nj}(z^{0})i$

(20)

for the uctuations of the projected potential.

We replace all the correlation functions in the equation of motion (13) by the expression (20). The time integration can be performed using the fact that the averaged density matrix h () i varies slow by on the correlation time scale $_{\rm c}$. Thus, h () i can be evaluated at time

t and taken out of the time integral. Finally, taking $_{\rm c}$ to zero, the Fourier transform of the kernel (14) leads to a product of delta functions in the spatial coordinates. Perform ing the remaining spatial integrations over z and z^0 , Eq. (13) reduces to

$$ih (I_{lk} h_{lk} (z;z^{0};t)i = \frac{i}{2h} \sum_{m n}^{X} [h S_{ln} (z) S_{nm} (z)ih_{mk} (z;z^{0};t)i$$

$$+ h S_{mk} (z^{0}) S_{nm} (z^{0})ih_{ln} (z;z^{0};t)i 2h S_{m} (z) S_{nk} (z^{0})ih_{mn} (z;z^{0};t)i]:$$
(21)

The trapping potential has N m in in a, i.e., the channel index n can be written as $n = (;n_x;n_y), = 1; ...;N$. We will now assume that the m in in a are well-separated in $\hat{x}\hat{y}$ -direction such that we can neglect all matrix elements S_{ij} with di erent trap labels . Under this assumption, the rst and second term on the right-hand side of Eq. (21) depend only on a single trap label. In the third term, the trap labels may be di erent for S_m as compared to S_{nk} . Since current noise in one particular wire generates uctuations of the magnetic eld in all trapping wells, there will be a correlation between the uctuations in di erent traps. It is hence this third term in Eq. (21) which describes the correlation between potential uctuations in di erent traps.

U sing Eq. (21) it is now possible to describe decoherence induced by current noise in trapping geom etries of one, two orm ore parallel wires [31, 32]. In the following sections we will discuss decoherence in two speci c trapping con gurations: the single-wire trap in Section IIIA, and the double-wire trap in Section IIIB, which is of particular interest for atom interferom etry experiments [20, 21, 22].

III. TRAPPING GEOMETRIES

W e will now consider two speci c trap con gurations, the single-wire trap and the double-wire trap. The dynam ics of the noise-averaged density matrix will be discussed using Eq. (21) which was derived in the previous section. We assume that the wire generating the potential uctuations is one-dimensional. This assumption is reasonable for distances r_0 of the trap minimum to the wire much larger than the wire width l_w and wire height l_h . Typical length scales are r_0 10 m to 1mm and wire widths and heights l_w 10 m to 50 m, l_{\star} 1 m [32].

To keep the notation short, we will suppress the brackets denoting the averaging. Thus, from now on, the density matrix $_{ij}$ denotes the average density matrix.

A. The single-wire trap

We are now looking at a speci c m agnetic trapping eld having only a single one-dimensional trapping well as shown in Fig.2. The magnetic eld is generated by the superposition of the magnetic eld due to the current I in the single w ire along the \hat{z} -axis and a hom ogeneous bias eld $B_{\text{bias}}^{(x)}$ parallel to the chip surface and perpendicular to the wire (see Fig. 1). We additionally include a hom ogeneous bias eld $B_{\text{bias}}^{(2)}$ parallel to the trapping well.

This longitudinal bias eld is experimentally needed to avoid spin ips at the trap center. Thus the magnetic eld has the form :

$$B(x) = \frac{{}_{0}I}{2} \frac{1}{x^{2} + y^{2}} \begin{pmatrix} 0 & 1 & 0 & B_{\text{bias}} \\ y & X & A + 0 & 0 \\ 0 & B_{\text{bias}} & B_{\text{bias}} \end{pmatrix} (22)$$

The minimum of the trapping potential is located above the wire $x_0 = 0$ and has a wire-to-trap distance of $r_0 = y_0 = {}_0 I = (2 B_{\text{bias}}^{(x)})$.

W e have now all the ingredients needed to calculate the uctuation-correlator h S_{m} (z) $S_{nj}(z^{0})i$. U sing Eqs. (8), (15), and (16) we obtain

h S_{im} (z) S_{nj} (z⁰)
$$i = A_{imnj} J (z z^{0})$$
: (23)

The transition matrix elements are given by

$$A_{im n j} = k_{B} T_{e} A \frac{{}_{0} g_{F B}}{Z} \frac{B_{bias}^{(x)}}{B_{bias}^{(z)}}^{2}$$

$$Z dr_{? i}^{(x)}(y y_{0}) m (r_{?}) \qquad (24)$$

$$Z dr_{? n}^{0}(r_{?}^{0})(y^{0} y_{0}) j (r_{?}^{0}):$$

The spatial dependence of the noise correlator is given by

$$J(z) = \frac{1}{r_0^5} \int_{1}^{Z_4} dz \ 1 + z^2 \int_{2}^{\frac{3}{2}} \frac{h}{1} + (z = r_0 z)^2 \frac{i}{2} \frac{3}{2} :$$
(25)

A more detailed derivation of the correlation function is given in Appendix A. The integration in Eq. (24) can be done explicitly using harmonic oscillator states for $_{n}$ (r₂), which is a good approximation as long as B^(z)_{bias} is of the order of B^(x)_{bias} and the wire-to-trap distance r₀ is much larger than the transverse width w of the trapped state. Both requirements are usually well satisfied in experiments. The dashed line in Fig.2 shows the harmonic approximation to the trapping potential. Using the harmonic approximation we can characterize the steepness of the trapping potential by its trap frequencies. It turns out that the two frequencies coincide,

$$! = \int_{m B_{\text{bias}}^{(z)}}^{S} \frac{\frac{2 B g_F}{m B_{\text{bias}}}}{M B_{\text{bias}}^{(z)}} \frac{B_{\text{bias}}^{(x)}}{Y_0}; \qquad (26)$$

i.e., the trap potential can be approximated by an isotropic 2d harm onic oscillator (2d-HO).

A fter integration we obtain

$$A_{imnj} = A_0 \quad i_x m_x \quad i_y m_y \quad n_x j_x \quad n_y j_y$$
; (27)

where

$$\gamma_{i_{y}m_{y}} = \frac{p_{m_{y}} + 1_{i_{y}m_{y}+1} + p_{m_{y}} + p_{m_{y}} + p_{m_{y}}}{m_{y} + p_{m_{y}} + p_{m_{y}}}$$
(28)

and the indices n_x , n_y denote the energy levels in x and y direction of the 2d-HO. The prefactor A_0 is

$$A_0 = k_B T_e A - \frac{_0 g_{F B}}{_B \frac{_{bias}}{_{bias}}} \frac{B_{\frac{_{bias}}{_{bias}}}}{B_{\frac{_{bias}}{_{bias}}}} \frac{w^2}{2}$$
 (29)

and $w = \frac{p}{h=(m!)}$ is the oscillator length of the harmonic potential.

Before moving on to derive the equation of motion for the averaged density matrix, let us discuss som e consequences of expression (27). Inspection of the coe cients A_{imnj} in Eq. (27) shows that there is no direct in uence onto the longitudinalm otion of the atom, since the matrix element A iijj vanishes. This result is not unexpected, because we consider only current uctuations along the wire, which give rise to uctuations in the trapping eld along the transverse directions of the trap potential. In fact, only transitions among energy levels of the \$-com ponent of the 2d-HO give a non-vanishing contribution. An explanation can be obtained by exam ining the change of the trap minimum position under variation of the current in the wire. Changing the current by I leaves the trap m in im um in x-direction unchanged at $x_0 = 0$, but shifts the \hat{y} -trap m in imum by $y_0 = 0$ I=(2 B_{bias}^(x)) [39]. Even though there is no direct coupling to the motion along the wire there can still be spatial decoherence in 2-direction as we will see in the nalresult for obtained from Eq. (21). However, this requires transitions to neighbouring transverse energy levels.

Substituting Eqs. (23) and (27) in Eq. (21) leads to an equation of motion for for the single-wire trap conguration. Instead of discussing the general equation of

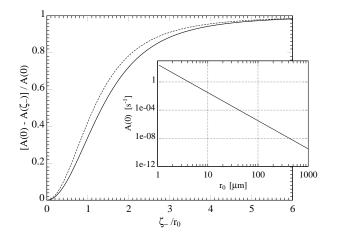


FIG. 3: Spatial dependence of the decay rate $_{dec}() = A(0) = A(0)$ A() for the diagonal elements $_{ii}(;t)$, Eq. (37). The wire-to-trap distance is $r_0 = 100$ m and the trap frequency is ! 2 10kHz. The dashed line is the approximation Eq. (39) for A(). Inset: Decay rate A(0) as function of r_0 . The parameters chosen in the plots correspond to 87 Rb trapped at $T_e = 300$ K in a magnetic trap with a gold wire of conductivity $_{Au} = 4.54$ 10^{2} m 1 and a cross-section of A = 2.5 m 5 m. The bias elds chosen are $B_{bias}^{(x)} = 80$ G and $B_{bias}^{(z)} = 2$ G.

motion of we will only consider the case where the two lowest energy levels of the transverse motion are taken into account. The restriction to the lowest energy levels corresponds to the situation of the atom ic cloud being mostly in the ground state of the trap and having negligible population of higher energy levels. This situation is realistic, if the energy spacing of the discrete transverse states is large com pared to the kinetic energy. Nevertheless, the result obtained from the two-level model provides a reasonable estimate for the decoherence of an atom ic cloud, even if m any transverse levels are populated. Equation (27) shows that only next-neighbour transitions are allowed. As A_{im nj} is a product of two next-neighbour transitions there can only be contributions of the next two neighbouring energy levels. Higher energy levels do only contribute to the decoherence by successive transitions which are of higher order in A im n j and hence are negligible.

W e rew rite Eq. (21) for the subspace of the two lowest eigenstates in a matrix equation for the density vector

$$= (_{00}; _{11}; _{10}; _{01}) : (30)$$

The indices of the averaged density matrix $_{\rm lk}$ denote the transverse state $l = (l_x; l_y)$ but we are only writing the l_y component of the labelas can only couple to states with the same x-state (i.e. only transitions between di erent y-states of the 2d-HO are allowed). The x-label is $l_x = 0$ for all states under consideration. Hence Eq. (21) can be written as a matrix equation for the density matrix

vector Eq. (30)
h i
ih@
$$H^{r}(z;z^{0})$$
 $(z;z^{0};t) = i\mathbb{K}^{r}(z z^{0})$ $(z;z^{0};t)$:
(31)

The matrix A is de ned as

where A () = $\frac{1}{h^2}A_0J($) and = z z^0 . The equations for the diagonal elements, i.e., $_{00}$, $_{11}$, and for the o -diagonal elements, i.e., $_{01}$, $_{10}$ decouple. However, the decoupling is a consequence of the restriction to the two lowest energy levels and is not found in the general case. Yet, the decoupling allows to nd an explicit solution for the time evolution of the diagonal elements. The matrix equation proves to be diagonal for the linear combinations $_{00}$ $_{11}$ and introducing the new coordinates = z z^0 , $_{+} = \frac{1}{2}(z + z^0)$ we obtain the general solution

 $_{k}$ (; +;t) = R_k ($\frac{hk}{m}$ t)e^{ik} + e * (;t)t; (33)

$$_{k}$$
 (;t) = A (0) $\frac{1}{t} \int_{0}^{2^{\circ}} dt^{0}A (\frac{hk}{m}t^{0})$: (34)

The function R_k is xed by the initial conditions, i.e. by the density matrix at time t = 0:

$$R_{k}() = d_{+}e^{ik_{+}} (; +; t=0):$$
 (35)

Note that in Eq. (34) is a function of the spatial variable and the wavevectork, and is in general not linear in the time argument t. Adding and subtracting the contributions nally leads to the following expressions for the diagonal elements of the density matrix

$${}_{00}(; +; t) = \frac{1}{2} \int_{1}^{2} \frac{dk}{2} [+ (; +; t) + k (; +; t)];$$
(36)

The result for $_{11}$ can be obtained from (36) by replacing the plus sign between the term s by a m inus sign. To get a feeling for the spatial correlations we trace out the center of m ass coordinate $_{\frac{1}{7}}$:

$$\begin{array}{rcl} & & & & \\ & & & \\ & & & \\ & & & \\ & &$$

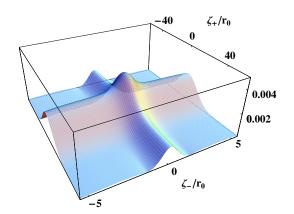


FIG. 4: Time evolution of j_{00} (; +;t) j after t = 2=A (0). Att = 0 the wavepacket is a G aussian wavepacket of spatial extent $w_z = 20r_0$. The wire-to-trap distance is $r_0 = 5$ m and all other parameters correspond to those used in Fig. 3. A (0) 0.5s¹ is given by Eq. (38). The density matrix shows damped oscillations which become more pronounced as + increases.

Equation (37) shows that we can distinguish two decay mechanisms. There is an overall decay of the spatial odiagonalelements with a rate dec() = [A(0) A()]. This decay only a ects the density matrix for € 0. thus suppressing the spatial coherence. The spatial correlation of the potential uctuations can be read o Fig. 3, showing dec (). We nd for the potential uctuations a correlation length _c of the order of the trap-to-chip surface distance c no. The correlation length c must not be confused with the coherence length describing the distance over which the transport of an atom along the trapping well is coherent. This coherence length is described by the decoherence time and the speed of the m oving wavepacket. The correlation length _c characterizes the distance over which the potential uctuations are correlated.

The second mechanism describes the equilibration of excited and ground state, quanti ed by the diagonalelements $_{00}(0;t)$, which occurs at a rate $_{pop}(0) = 2A(0)$. Here equilibration means that, due to this mechanism, the probability to be in the ground state, i.e. $_{00}(0;t)$, tends to 1/2. Of course, at the same time the probability $_{11}(0;t)$ to be in the excited state approaches 1/2 at the same rate. Note, that for the spatial o -diagonal matrix elements the equilibration rate depends on .

W e will now take a closer look onto the quantity A (0) for realistic trap parameters. Using J (0) = $\frac{3}{8y_0^5}$ and Eq. (26), Eq. (29) leads to

$$A(0) = \frac{3}{2} k_{\rm B} T_{\rm e} \quad A \frac{B_{\rm bias}^{(x)}}{2 \, h \, m} \, \frac{0}{4}^{2} \, \frac{2_{\rm B} g_{\rm F}}{B_{\rm bias}^{(z)}} \, \frac{1}{r_{0}^{4}} :$$
(38)

The inset of Fig. 3 plots A (0) over r_0 for reasonable trap parameters. Equation (38) shows that the decay rate is

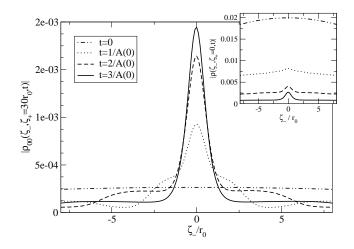


FIG. 5: Decay of the absolute value j_{00} (; + = $30r_0$;t)j and j_{00} (; + = 0;t)j (inset). The wave packet is a Gaussian wavepacket of spatial extent $w_z = 20r_0$ at t = 0. The wire-totrap distance is $r_0 = 5$ m. All other parameters are the same as used in Fig. 3. A (0) $0.5s^{-1}$ is given by Eq. (38). The dashed line (t = 2=A (0)) corresponds to cuts of Fig. 4 along

for + = $30r_0$ (inset $_+$ = 0). Spatial correlations of the potential uctuations are restricted to a narrow band around

= 0. The width of this band is on the order of r_0 . The density m atrix shows dam ped oscillations which become more pronounced with increasing +. The increase of j₀₀ (; + = $30r_0$;t) jfor increasing timet is a consequence of the spreading of the wavepacket.

scaling on the wire-to-trap distance as $1=r_0^4$ giving a rapid increase of decoherence e ects once the atom ic cloud is brought close to the wire.

As speci c example we want to study the time evolution of the full density matrix in the ground state. Figure 4 and Fig.5 show the time evolution of the absolute value of the density matrix element j_{00} (; +;t) j for a G aussian wave packet of spatial extent $w_z = 20r_0$ and a wire-to-trap distance of $r_0 = 5$ m. Initially, at time t = 0 all other elements of the density matrix are zero. The time evolution is calculated for the reduced subspace using Eq. (33) and Eq. (36). For the spatial correlation we use the approximation (dashed line in Fig. 3)

A ()
$$4\frac{A_0}{h^2r_0^5}$$
 $\frac{32}{3}$ $+$ $\frac{2^{\#}}{r_0}$: (39)

The time evolution of the Gaussian wavepacket shows a strip of j $j < l_c$ 10 in which the density matrix decays much slower. This is a consequence of the dependence of the decay rate shown in Fig. 3. The spatial correlation length of the wavepacket can hence be read of Fig. (5) as l_c 10. In addition, a damped oscillation in the relative coordinate is arising which is getting more pronounced for larger values of $_+$. Figure 5 shows cuts along the -direction for di erent values of $_+$. The origin of the damped oscillations is the k-dependence of the equilibration and decoherence mech-

anism described by $_{k}$ in Eq. (34). To demonstrate the in uence of the k-dependent damping we assume that $_{k} = A(0)$ [A()+ (;t)k]. Choosing linear in k leads to a modulation of the density matrix by a factor proportional to $\cosh(i_{0} + _{1})$, describing damped oscillations. The $_{0=1}$ are real functions of and t. The oscillations arise only for non-vanishing . Decay rates which are k-independent do not show oscillations.

The decay described by $_{k}$ in Eq. (34) is how ever not linear, but includes higher powers in k. Hence the simple linear model $_{k} = A(0)$ [A()+(;t)k] describes the oscillations in Fig. 4 and Fig. 5 only qualitatively.

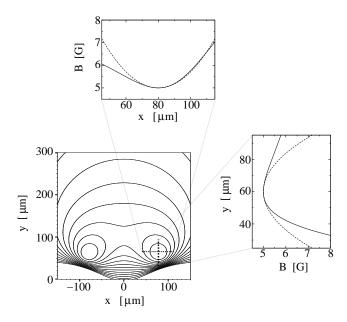


FIG.6: Contour-plot of the magnetic eld in the double-wire geometry for $B_{bias}^{(x)} = 10G$, $B_{bias}^{(z)} = 5G$, and I = 0.3A. The wires are located at x = 100 m and y = 0. Two potential minima are located roughly above the current-carrying wires. The upper (right) plot shows a horizontal (vertical) cut through the right potential minimum. The dashed lines in the upper and the right plot show the harm onic approximation to the trapping eld.

B. The double-wire trap

The second con guration which we discuss is a doublewire trap [20]. A system of two parallel trapping wells is of special interest for high-precision interferom etry [20, 21, 22] or beam -splitter geom etnies [40]. The e ect of decoherence is one of the key issues in these experiments.

Form and characteristic of the double-w ire trap is described in [20, 32] so that we will only brie y introduce the main features of the double-w ire trapping potential. Figure 1b shows the setup for the trapping eld, which is generated by two in nite w ires running parallel to the \hat{z} -axis, separated by a distance d, and a superposed hom ogeneous bias eld $B_{\rm bias}^{(x)}$ perpendicular to the current direction. A second bias eld pointing along the 2- direction, B_{bias}, is added in experim ental setups to avoid

$$B(\mathbf{x}) = \frac{\begin{array}{c}2}{2} & 0 & 1 \\ \frac{1}{2} & \frac{1}{x + \frac{d}{2}^{2} + y^{2}} \\ \frac{1}{x + \frac{d}{2}^{2} + y^{2}} & 0 \\ 0 & \frac{y}{x + \frac{d}{2}^{2} + y^{2}} \\ 0 & \frac{1}{x + \frac{d}{2}^{2} + \frac{1}{x + \frac{d}{2}^{2} + y^{2}} \\ 0 & \frac{1}{x + \frac{d}{2}^{2} + \frac{1}{x + \frac{1}{x + \frac{d}{2}^{2} + \frac{1}{x + \frac{1}{x + \frac{1}{x + \frac{d}{2}^{2} + \frac{1}{x + \frac{1}{x + \frac{1}{x + \frac{1}{x + \frac{1}{x + \frac{1}{x + \frac{1}{x$$

There are two di erent regimes for the positions of the trap-minima. De ning a critical wire separation $y_0 = {}_0I=(2 B_{\rm bias}^{({\rm X})})$ we can distinguish the situation of having $d > 2 y_0$ where the trap minima are breated on a horizontal line at $x_0^{\rm L=R} = \frac{1}{d^2=4} \frac{2}{g}$ and $y_0 = y_0$, and the situation of $d < 2 y_0$ where the trap minima are positioned on a vertical line at $x_0 = 0$ and $y_0 = y_0 - \frac{1}{y_0^2} - \frac{2}{d^2=4}$. The two trap minima overlap and form a single minimum for $d = 2 y_0$.

2 y since in this con guration we have two horizontally spaced, but otherwise identical trap minima. The two trap minima form a pair of parallel waveguides. This kind of geometry has been suggested for an interference device [20, 21]. Figure 6 shows a contour-plot of the double trap in the d > 2 y regime.

W e now analyze the double-wire setup along the lines of Section IIIA. Firstly, an explicit expression for the correlation function h S_{im} (z) $S_{n\,j}\,(z^0)\,i$ is needed. A fler som e calculation we obtain

Further on we will restrict ourselves to the regimed >

$$h S_{im} (z) S_{nj} (z^{0}) i = A_{0} \frac{8}{w^{2}} \frac{x_{0} x_{0}}{d^{2}} \qquad X \qquad Z \qquad Z \qquad Z \qquad (41)$$

$$= L_{R} \qquad = L_{R}$$

where the spatial correlation is now given by

$$J (z z^{0}) = dz x_{0} \frac{d}{2}^{2} + y_{0}^{2} + z^{2} x_{0} \frac{d}{2}^{2} + y_{0}^{2} + (z z^{0} z^{0})^{2}$$
(42)

Here, is the trap label corresponding to i and ${\tt m}$, and

the trap label corresponding to n and j, the indices which occur in h S_{im} (z) S_{nj} (z⁰)i. The wires are located at $x = d_{L=R} = d=2$ and is de ned as $_{L} = 1$, $_{R} = 1$. The result Eq. (41) uses the assumption that the extent of the wavefunction w ism uch sm aller than y_0 and m uch sm aller than the trap m inimum o set $\dot{y}_0^{L=R}$ j from the \hat{x} -axis, i.e., w $\dot{y}_0^{L=R}$ j and w y_0 . This approximation breaks down if the wire separation d approaches the critical separation distance 2 y at which the two trap m inim a merge.

Instead of going into details of the derivation we will discuss the di erent contributions qualitatively. As the system is invariant under mirror in aging at the 2^{-2} -plane, corresponding to an invariance under interchange of the left (L) trap and right (R) trap label, only the following three contributions have to be distinguished (see

Fig.7).

- (a) The in uence of current uctuations in the left wire onto an atom in a state which is localized in the left arm of the trapping potential (Fig. 7a).
- (b) The in uence of current uctuations in the left wire onto an atom which is in a superposition of a state localized in the left arm and a state localized in the right arm of the trapping potential (see Fig. 7b).
- (c) The in uence of current uctuations in the left wire onto an atom in a state which is localized in the right arm of the trapping potential (Fig. 7c).

All other contributions are obtained by symmetry operations. Contribution (a) is given by the term proportional to J_{LL}^{L} and is the dominating decoherence source

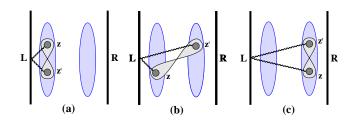


FIG. 7: Contributions of the noise in the left wire to the decoherence of $_{ij}(z;z^0;t)$. The gures show only the coupling of one point on the wire to the atom ic state. To get the total contribution to the decoherence an integration over all wire elements coupling to the atom ic state has to be perform ed.

		$J_{\rm LL}^{\rm L}$ ($~$)	$J_{ m LR}^{ m L}$ ()	$J_{RR}^{\rm L}$ ()
	= 0	$\frac{1}{y_0^5}$	$\frac{2}{y_0^2 d^3}$	1 d ⁵
	Уо	$\frac{1}{y_0^5}$	$\frac{2}{d^3 y_0^2}$ 1 $\frac{3}{2} \frac{y_0^2}{d^2}$	$\frac{1}{d^5}$
У0	d	$\frac{4}{y_0^2 3}$	$\frac{2}{d^3 y_0^2}$ 1 $\frac{3}{2} \frac{2}{d^2}$	$\frac{1}{d^5}$
d		$\frac{4}{y_0^2 3}$	$\frac{2}{3}$ $\frac{1}{y_0^2}$ + $\frac{1}{d^2}$	$\frac{4}{d^2 3}$

TABLE I: Estimate of the contributions to the decoherence. The columns for J_{LL}^{L} , J_{LR}^{L} , and J_{RR}^{L} correspond to contributions (a), (b) and (c) of Fig. 7 respectively. The J () are given by Eq. (42) as a function of $z = z = z^{0}$. The approximation assumes y_{0} d.

in the regime $d > 2 y_0$, as all other contributions (J_{LR}^L , J_{RR}^L shown in the third and forth column of Table I) are suppressed by orders of $y_0=d$.

The contribution in Fig.7b is of particular interest as it describes the cross-correlations between the noise in the left and right trapping well i.e. given by term s proportional to J_{RL}^{L} and J_{LR}^{L} . Current uctuations in one of the wires give rise to magnetic eld uctuations in all the trapping wells. Magnetic eld uctuations are therefore not uncorrelated. These correlations are however suppressed for y_{1} d as can be seen in Table I.

Contributions of type (c), given by term s proportional

to $J_{R\,R}^L$, are the smallest contributions to decoherence as they describe the in uence of the left wire current noise onto the atom ic cloud in the more distant right trap. Term s of type (c) are thus negligible for wire distances d 2 y as the magnetic eld decreases with 1=r and

uctuations in the trapping eld are dom inated by the nearest noise source i.e. contributions of type (a). In analogy to the proceeding Section IIIA we are going to approximate the transversal wavefunctions n = p = q. (41) by 2d-HO states. However one has to be careful as this approximation holds only if the two trapping wells are su ciently separated such that the mutual distortion of magnetic eld is small. If the distance between the two traps gets close to the critical value $d = 2 y_0$, a double-well structure arises and the harm onic approxim ation breaks down.W e estim ate the validity of the approxim ation by calculating the distance d_c at which the local potential maximum, separating the two trapping wells, is of the order of the ground state energy of the isolated single trap. The trap frequency for the double-wire con quration extracted from the harm onic approximation is

$$!_{d} = 2! \frac{\dot{x}_{0} \dot{j}}{d} = 2! \frac{p}{d^{2} = 4} \frac{2}{g};$$
 (43)

where ! is the single-wire trap frequency given in Eq. (26). Thus the ground state energy $E_0 = h$! of the single-wire trap corresponds to the limit of in nite separation d = 1. This energy E_0 is the maximum value for the ground state energy h_d of the double-wire trap under variation of d. Hence E_0 is an upper bound for the ground state energy of the double well in the case $d > y_0$. Using the procedure described above, we get the condition $d > 8 y_0$, restricting the region in which the transversal potential can be approximated as two independent 2d-HOs. The dashed line in Fig. 6 shows an example for the double-wire setup.

Perform ing the integration over the transverse coordinates $r_{\rm ?}$, using 2d-H 0 states for $_{\rm n}$, gives transition m atrix elements

where the functions $\tilde{}_{ij}$ have been de ned in Eq. (28). For simplicity we choose the current in the left and right wire to be the same for the derivation of Eq. (45).

C om paring the matrix elements obtained in Eq. (45) with those in Eq. (27) for the single-wire trap, we discussed in Eq. (27) for

the following di erences. First of all it has to be noted that the transitions are no longer restricted to the \hat{y} -components of the 2d-HO. This is a direct consequence of the geometry as the positions of the trap minim a are now sensitive to current uctuations in \hat{x} -and \hat{y} -direction

whereas the x-position for the single-wire trap minimum was independent of the current strength in the conductor. Secondly, the prefactor of the transition matrix element in Eq. (45) is now a function of the spatial coordinates x_0 , taking the geometric changes of the trap minimum position under variation of the wire separation d into account.

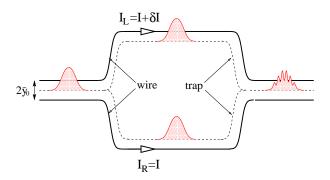


FIG. 8: Schem atic setup of an interferom eter for cold atom s using a double-wire trap. A wavepacket is coming in from the left single waveguide form ed by a double wire trap with a wire spacing of $d = 2y_0$. The wavepacket is split into a coherent superposition of states localized in the left and right arm of the double waveguide. Inducing a potential di erence, e.g. by applying a current di erence I in the left and right wire, gives rise to a phase shift. R em erging the wavepackets results into an interference pattern in the atom density. For a m ore detailed description of atom interferom eters of this type see R ef. [21].

Inserting Eq. (45) in Eq. (21) leads to a set of equations for the dynam ics of the averaged density matrix. For simplicity we restrict ourselves to the ground state and

rst excited state of the 2d-HO.Having in m ind a spatial interferom eter as suggested in Ref. 21, the most interesting quantity is the density matrix element describing the coherent superposition of a state in the left arm with a state in the right arm . Figure 8 shows the geometry of the interferom eter. A wavepacket is initially prepared on the left side in a single trap. The wavepacket propagates towards the right and is split into a coherent superposition of a state in the left arm with a state in the right arm. Finally, applying a small o set between the currents in the left and right wire gives rise to a phase shift between the two wavepackets which results, after recom bination, in a fringe pattern of the longitudinal density. For a more detailed description of atom interferom eters of this type we refer to [21]. Loss of coherence between the wavepackets in the left and right arm, due to current

uctuations in the conductors, will decrease the visibility of the interference pattern. We will thus study the decay of the components of the density matrix o -diagonal in the trap index. We will suppress the trap label (L/R) in all following expressions, bearing in m ind that the left (right) index of will always denote a state in the left (right) trap.

W e will assume that the incoming wavepacket is ini-

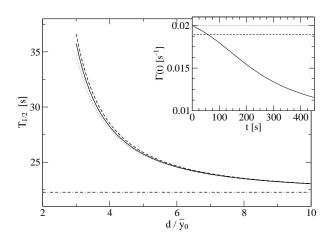


FIG. 9: Decay time in the double-wire trap. $T_{1=2}$ is de ned as the time it takes until $\begin{array}{c} 00\\00\\00\end{array}$ (z; z⁰;t) has decayed to half of its initial value at t = 0. The graph shows its dependence on the wire separation d if all contributions in Eq. (46) are taken into account (solid line), if the cross-correlations $_{1}$ are neglected (dotted line), and in the limit of d y₀, Eq. (52) (dashed line). The dash-dotted line is the $T_{1=2}$ -time using the decay rate Eq. (38) for the single-wire con guration. Inset: (t) $\ln \left(\begin{array}{c} 00\\00\end{array} \right)$ =t at d = 3y₀. The trap-chip surface distance taken for the plot is y₀ = 10 m and all other trap param eters correspond to those used in Fig. 3.

tially split into a symmetric superposition of the left and right arm. In addition we will choose the currents in the left and right wire to be same, $I_L = I_R$, which does not restrict the validity of the obtained result for the decoherence e ects but keeps the equations simple as the full symmetry of the double-wire geometry is still conserved. The dynamics of $(z;z^0;t)$ is obtained from Eq. (21), leading to a matrix equation in analogy to Eq. (31) but with a density matrix vector

where the upper index denotes the \hat{x} -state and the lower index the \hat{y} -state of the 2d-HO. The left (right) pair of indices refers to a state in the left (right) well. Them atrix A is

$$A^{*} = \begin{bmatrix}
 0 & P & & & & & 1 \\
 B^{*} & 1 & 1 & 2 & 3 & 4 \\
 1 & 1 + 3 & 0 & 6 & 5 & C \\
 2 & 0 & 2 + 4 & 5 & 6 & C \\
 3 & 6 & 5 & 1 + 4 & 0 & A \\
 4 & 5 & 6 & 0 & 2 + 3 \\
 (46)$$

Here, terms labelled by $_{i}$ are contributions of the type shown in Fig. 7a plus the corresponding term of type Fig. 7c. Terms denoted by $_{i}$ are cross-correlations as described by contributions shown in Fig. 7b. The terms abbreviated as do not depend on the longitudinal coordinate z, z^{0} whereas the cross-correlations are functions of (z z^{0}).

We will assume that the extent of the wavepacket w_z along the trapping well is w_z d. As the crosscorrelations i vary on a length scale of approximately d, we can replace i(z z^2) in Eq. (46) by the constant i(0) [41].

Further on we will assume that at t = 0 the density matrix is given by:

Figure 9 shows the time $T_{1=2}$ it takes until $\begin{array}{c} 00\\00 \end{array}$ (t = 0) has decayed to half of its initial amplitude as a function of the wire separation d. W e assume the average currents in the wires to be constant and we vary only the separation length d. Thus the position of the trap minim a given by

$$y_0 = y_0 \qquad ; \qquad (48)$$

$$\mathbf{x}_{0}^{L=R} = \frac{1}{d^{2}=4} \frac{2}{3};$$
 (49)

m ove horizontally to the surface, leading to a w ire-to-trap distance of

$$\mathbf{r}_{0} = \frac{\mathbf{d}}{\frac{\mathbf{p}}{2}} \mathbf{1} \quad \mathbf{1} \quad \frac{\mathbf{y}_{0}^{2}}{\mathbf{d}^{2}} \quad \mathbf{z} \quad (50)$$

The solid line in Fig. 9 shows the $T_{1=2}$ time obtained from the solution of Eq. (31) using Eq. (46) in the approxd.C ross-correlation imation _i (z z⁰) $_{i}$ (0) for w $_{z}$ term s $_{i}$ play how ever only a m inor role for the $T_{1=2}$ time as can be seen from the dotted lines in Fig. 9, showing the case where the $_{i}$ terms are neglected in Eq. (46). The cross-correlation term s, shown in Fig. 7b, include term s describing positive correlation between potential uctuations, suppressing the decoherence, but also negative correlation between potential uctuations which enhance the decoherence. Figure 10 shows schem atically the potential uctuations V induced by a current uctuation I in the left wire.

The inset of Fig. 9 shows the change of the decay rates over time. Taking the full matrix Eq. (46) into account (solid line) there is a change of decay rate $_{+}$ (t) towards a slower decay rate for t $_{+}^{1}$ (0). If the cross-correlations are ignored, the decay rate is constant

 $_+$ (0). Inspection of A', given by Eq. (46), show s that neglecting the term s $_{\rm i}$ decouples $_{\rm 00}^{\rm 00}$ from the excited states leading to an exponential decay with a single decay rate.

We nally discuss the decoherence for large distances d between the wires, i.e., d y. For d y it is sufcient to take only the in uence of $_{1}I$ (I_{e}) onto the left (right) trap (given by contributions of type F ig. 7a) into account, as all other contributions are strongly suppressed by orders of y=d (see Table I). Hence the matrix Eq. (46) decouples $_{00}^{00}$ from the excited states and the remaining equation for $_{00}^{00}$ can be solved analytically. The solution is

$$\sum_{00}^{00} (z; z^{0}; t) = e^{t} e^{\frac{1}{h} H t} \sum_{00}^{00} (z; z^{0}; 0); \quad (51)$$

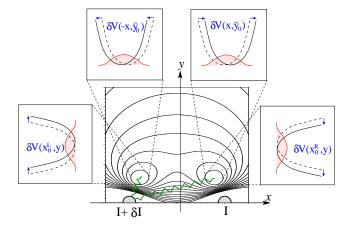


FIG.10: In uence of current uctuations I in the left wire onto the potential of the trapping wells V (x;y) = hS j ß iB. The potential uctuations V (x;y_0) = V (x;y) are reaction symmetric about the ŷ-2-plane for jx $x_0^{L=R}$ j y₀. Hence the uctuations in %-direction are conserving the symmetry of the trapping potential. This leads to positive correlations in h S_{im} (z) S_{nj}(z⁰) is suppressing the decoherence. The uctuation in ŷ-direction, V (x_0^L ;y), V (x_0^R ;y), show negative correlative correlations giving rise to an increase in the decoherence rate.

where \hat{H} is the free H am iltonian as de ned in Section IIA. The decay rate is given as

11

$$= \frac{3}{2 h^2} A_0 \frac{\mathbf{\dot{x}}_0 \mathbf{\dot{f}}}{d^2} + \frac{1}{(\mathbf{\dot{x}}_0 \mathbf{j} + d=2)^2} \frac{\pi}{r_0^5} \frac{1}{r_0^5} : \qquad (52)$$

#

y, Eq. (52) reduces to the decay rate ob-In the lim it d tained for the single-wire con guration, Eq.(38), shown by the dash-dotted horizontal line in Fig. 9. However, there is no spatial dependence of along the longitudinal direction (z z^{2}) in the case of widely separated trapping wells. P lotting the $T_{1=2}$ time for the approximation given by Eq. (51) (dashed line in Fig. 9) using the decay rate Eq. (52), shows a good agreem ent of the approximation with the exact solution as soon as d is of the order of several y. Comparing all three graphs of Fig. 9 one can conclude, that the increase in $T_{1=2}$ with decreasing separation d is due to geom etric changes of the trap positions. An increase of the wire-to-trap distance r_0 due to a decrease of d, leads to an increase in the $T_{1=2}$ time as the rate of the dom inating decoherence source scales with $1=r_0^4$.

${\tt IV}$. ${\tt CONCLUSION}$

Using the density-matrix formalism, we derived an equation of motion Eq. (13) to describe the consequences of current uctuations on a cold atom ic cloud in a microchip trap. The model allows the description of decoherence in multiple wire traps [31, 32], as well as more com plex guiding systems required for the implementation of a beam splitter [13] or interference experiments [20, 21, 22].

The atom trap was modelled as a multi-Channel 1dwaveguide, where di erent channels describe di erent transverse modes of the waveguide. A ssum ing 1d-wires on the atom ic chip, we examined the in uence of current uctuations along the wire onto the coherence of the atom cloud in the waveguide. We found that important contributions to the decoherence arise from transitions to neighbouring excited states.

We used this model to exam ine decoherence e ects for two speci c trapping con gurations: the singlewire waveguide and the doublewire waveguide. In both con-

gurations, decoherence of the ground state was discussed, taking processes from transitions to the states into account.

The single-wire trap showed for the ground state a decoherence rate which scales with the wire-to-trap distance r_0 as $1=r_0^4$. The potential uctuations are correlated over a length scale r_0 . As a consequence the decoherence rate is a function of the relative coordinate $z = z^0$. Using trap parameters based on present experiments [32] we obtained decoherence rates for $r_0 = 10$ m of the order of $0.03s^1$.

Extending the system to a double-wire waveguide enabled us to study decoherence for atoms in a superposition of a state localized in the left arm and a state localized in the right arm . This superposition is the basic ingredient for interference experiments. Approaching the two trapping wells, as is necessary for the splitting and merging of the wavepackets, showed a decrease in the decoherence rate. The decrease arises mostly due to geometrical rearrangements of the trap minima in the system. Cross-correlation e ects proved to be of minor im portance in our model. W e found an explicit expression for the decoherence rate Eq. (52) in the lim it of a w ire-to-trap distance r_0 m uch sm aller than the separation of the two wires d. This decoherence rate approaches the value for the single wire waveguide, = A(0), for decreasing $r_0 = d$.

The decay rates extracted in this model are small for distances realized in present experiments [32]. However we expect that further improvement in micro-structure fabrication and trapping techniques will decrease the trap-surface distance to scales at which the decoherence from transitions to transverse states may have a considerable in uence on trapped atom ic clouds.

A cknow ledgm ents

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APPENDIX A:DERIVATION OF THE PROJECTED POTENTIAL CORRELATOR

This section gives a derivation of the correlation function h S_{im} (z) $S_{n\,j}$ (z⁰)i. A general expression of the potential uctuation correlator h V (x) V (x) if for N parallel traps will be derived, from which h S_{im} (z) $S_{n\,j}$ (z⁰)i can be calculated using Eq. (8). Finally Eqs. (23–25) and Eq. (41), Eq. (42) can be obtained by specifying the geom etries specializing to the single and double-w ire trap con gurations.

The uctuations of the trapping potential V is induced by current noise in the wires which gives rise to a uctuating eld B. The trapping potential V and the magnetic trapping eld B are linked by Eq. (1), which enables us to express h V (x) V (x^0) i in term sofm agnetic all uctuations:

eld uctuations:

Thus the rst step is to nd the expression for $h B_i(x) B_j(x^0)i$ as a function of the current noise. We start by calculating A and B using

$$A_{i}(\mathbf{x}) = \frac{0}{4} d^{3} \mathbf{x} \frac{\mathbf{j}(\mathbf{x})}{\mathbf{j}\mathbf{x} \cdot \mathbf{x}\mathbf{j}}; \qquad (A2)$$

$$B_{i}(x) = \int_{jk} ijk \frac{d}{dx_{j}} A_{k}(x) :$$
 (A 3)

The current density in the set of 1d-wires is

$$j(x) = I(z) (x d) (y)2;$$
 (A 4)

where d denotes the \hat{x} -position of the -th wire. The sum over re exts the fact that the total current density j is a sum of M contributions to the current density arising from the set of M wires. We will now insert Eq. (A 4) in Eq. (A 2) and Eq. (A 3) to obtain an expression for the magnetic eld induced by the current in the wire array:

The correlation function for the current density is now assumed to be of the form

h I (z) I (
$$z^0$$
) i = 4 k_B T_e A (z \ddot{z}) (A6)

for the reasons discussed before in Section IIC. Using Eq. $(A \ 6)$ in combination with equations $(A \ 1)$ and $(A \ 5)$

gives the desired relation for the correlation function of the potential uctuations

h V (x) V (x) i = 4k_BT_e A
$$\frac{0}{4}^{2}$$

X X
hS (x) j j f (x) i hS (x⁰) j j f (x⁰) i (A 7)
ij
Y_{ij} (x; x⁰) J (x; x⁰);

where the following abbreviations have been introduced

$$J (x; x^{0}) = dz (x d)^{2} + y^{2} + (z z)^{2} \frac{3}{2}$$

$$(x^{0} d)^{2} + y^{02} + (z^{0} z)^{2} \frac{3}{2} : (A 9)$$

Equation (A 9) can be further simplified if the transversal positions $x^{(0)}$ and $y^{(0)}$ are replaced by the position of the trap minimum x_0 and y_0 where is the trap label denoting the trap in which the wavefunction is localized. The replacement of the transversal coordinates by its trap minim a positions is a good approximation as the transversal widths w of the trapped atom ic clouds are in general much smaller than the wire-to-trap distance r_0 . We have thus reduced J to a function which now only depends on the difference = $z = z^2$:

$$J () = \frac{z^{4} h}{dz^{0} (x_{0} d)^{2} + y_{0}^{2} + z^{0^{2}}}$$

$$A = \frac{1}{(x_{0} d)^{2} + y_{0}^{2} + (z^{0})^{2}}$$

$$A = \frac{1}{(x_{0} d)^{2} + y_{0}^{2} + (z^{0})^{2}}$$

where we shifted the integration variable to $z^0 = z$ z. Applying the form ula to the single and double wire congurations leads to Eq. (25) and Eq. (42) respectively.

To obtain h V (x) V (x) i using Eq. (A 7), we still need to calculate the m ean value of the atom ic m agnetic m om ent hS (x) j β (x) i. We assume that the m agnetic m om ent follows the m agnetic trapping eld adiabatically which is reasonable as long as the Larm or precession $!_{\rm L} = {}_{\rm B} B = h$ is fast compared to the trap frequency !. Calculating the spinor β (x) i for an atom having spin F = 2, either by considering the small corrections of the transversalm agnetic eld to $B_{\rm bias}^{(2)}$ perturbatively or by calculating the rotation of the spinor as the atom ic m om ent follows the trapping eld adiabatically, results in the follow ing expression for the spatial dependence of β (x) i for sm all deviations from the trap m inim um :

$$\beta(x)i = \frac{1}{2};2i + \frac{B_x(x) + iB_y(x)}{B_{bias}}$$

$$2;1i: \qquad (A 11)$$

The spin states are denoted as $f;m_F$ i and the spin quantisation axis is chosen along the 2-axis. Making use of Eq. (A11) leads to

hS (x) j fS (x) i = 2 _B
$$g_F \frac{B(x)}{B_{bias}^{(z)}}$$
; (A 12)

which is an approximation to the mean value of the magnetic moment to rst order in $B_2 = B_{\text{bias}}^{(z)}$. Inserting the expression for the magnetic moment Eq. (A 12) into Eq. (A 7) and inserting the speci c magnetic trapping eds for the single-wire trap, Eq. (22), or the double-wire trap, Eq. (40), we nally obtain the results for h S_{im} (z) $S_{\text{nj}}(z^0)$ i given by Eq. (24) for the single-wire setup and by Eq. (41) for the double-wire setup.

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